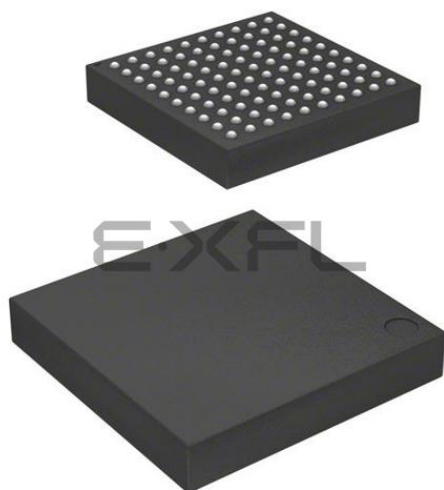




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Details

Product Status	Not For New Designs
Core Processor	RX
Core Size	32-Bit Single-Core
Speed	50MHz
Connectivity	EBI/EMI, I ² C, SCI, SPI
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	84
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	8K x 8
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	1.62V ~ 5.5V
Data Converters	A/D 16x12b; D/A 2x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-TFLGA
Supplier Device Package	100-TFLGA (5.5x5.5)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f52105bdla-u0

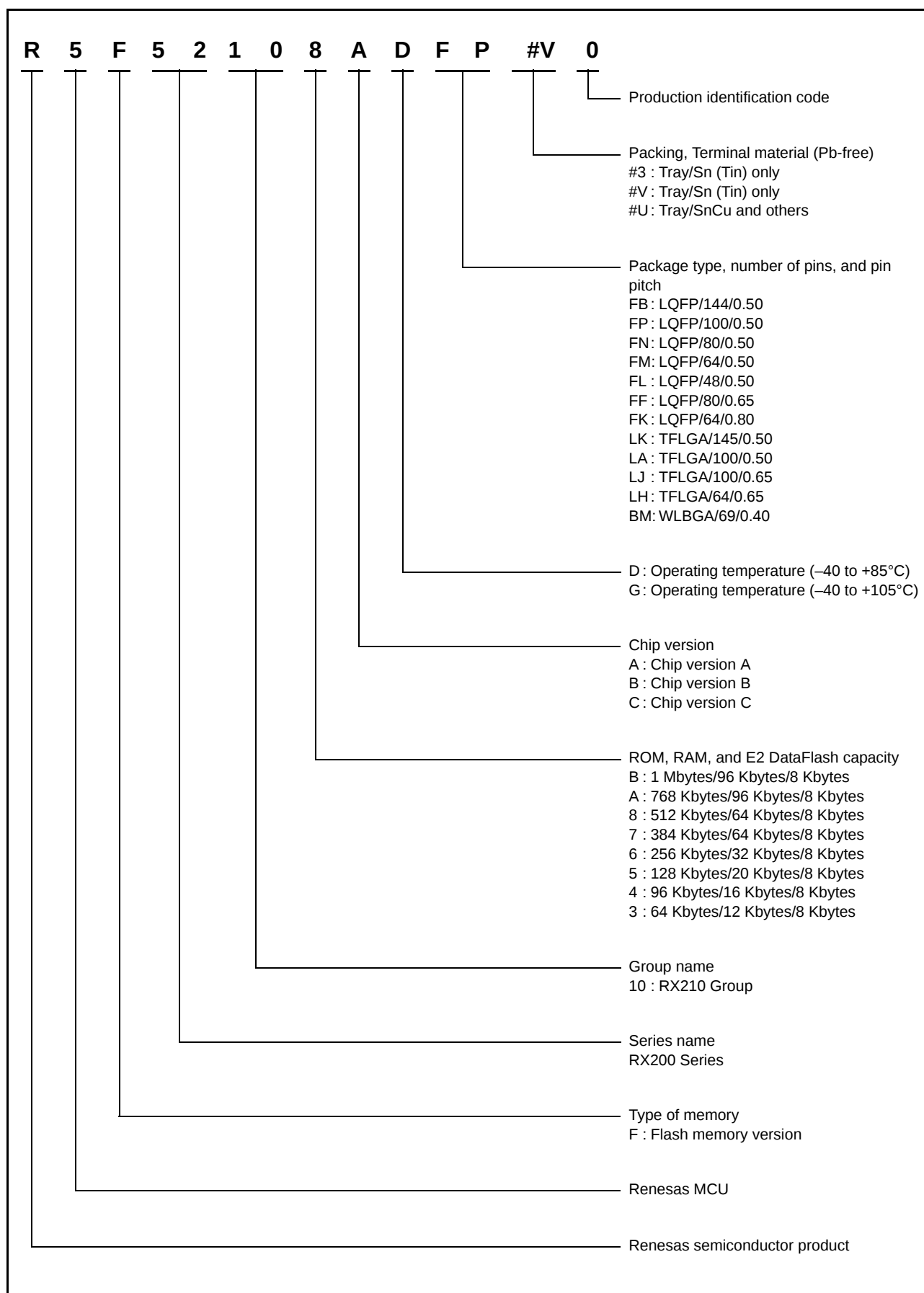


Figure 1.1 How to Read the Product Part No., Memory Capacity, and Package Type

Table 4.1 List of I/O Registers (Address Order) (2 / 29)

Address	Module Symbol	Register Name	Register Symbol	Number of Bits	Access Size	Number of Access Cycles	
						ICLK ≥ PCLK	ICLK < PCLK
0008 201Dh	DMAC0	DMA software start register	DMREQ	8	8	2 ICLK	
0008 201Eh	DMAC0	DMA status register	DMSTS	8	8	2 ICLK	
0008 201Fh	DMAC0	DMA activation source flag control register	DMCSL	8	8	2 ICLK	
0008 2040h	DMAC1	DMA source address register	DMSAR	32	32	2 ICLK	
0008 2044h	DMAC1	DMA destination address register	DMDAR	32	32	2 ICLK	
0008 2048h	DMAC1	DMA transfer count register	DMCRA	32	32	2 ICLK	
0008 204Ch	DMAC1	DMA block transfer count register	DMCRB	16	16	2 ICLK	
0008 2050h	DMAC1	DMA transfer mode register	DMTMD	16	16	2 ICLK	
0008 2053h	DMAC1	DMA interrupt setting register	DMINT	8	8	2 ICLK	
0008 2054h	DMAC1	DMA address mode register	DMAMD	16	16	2 ICLK	
0008 205Ch	DMAC1	DMA transfer enable register	DMCNT	8	8	2 ICLK	
0008 205Dh	DMAC1	DMA software start register	DMREQ	8	8	2 ICLK	
0008 205Eh	DMAC1	DMA status register	DMSTS	8	8	2 ICLK	
0008 205Fh	DMAC1	DMA activation source flag control register	DMCSL	8	8	2 ICLK	
0008 2080h	DMAC2	DMA source address register	DMSAR	32	32	2 ICLK	
0008 2084h	DMAC2	DMA destination address register	DMDAR	32	32	2 ICLK	
0008 2088h	DMAC2	DMA transfer count register	DMCRA	32	32	2 ICLK	
0008 208Ch	DMAC2	DMA block transfer count register	DMCRB	16	16	2 ICLK	
0008 2090h	DMAC2	DMA transfer mode register	DMTMD	16	16	2 ICLK	
0008 2093h	DMAC2	DMA interrupt setting register	DMINT	8	8	2 ICLK	
0008 2094h	DMAC2	DMA address mode register	DMAMD	16	16	2 ICLK	
0008 209Ch	DMAC2	DMA transfer enable register	DMCNT	8	8	2 ICLK	
0008 209Dh	DMAC2	DMA software start register	DMREQ	8	8	2 ICLK	
0008 209Eh	DMAC2	DMA status register	DMSTS	8	8	2 ICLK	
0008 209Fh	DMAC2	DMA activation source flag control register	DMCSL	8	8	2 ICLK	
0008 20C0h	DMAC3	DMA source address register	DMSAR	32	32	2 ICLK	
0008 20C4h	DMAC3	DMA destination address register	DMDAR	32	32	2 ICLK	
0008 20C8h	DMAC3	DMA transfer count register	DMCRA	32	32	2 ICLK	
0008 20CCh	DMAC3	DMA block transfer count register	DMCRB	16	16	2 ICLK	
0008 20D0h	DMAC3	DMA transfer mode register	DMTMD	16	16	2 ICLK	
0008 20D3h	DMAC3	DMA interrupt setting register	DMINT	8	8	2 ICLK	
0008 20D4h	DMAC3	DMA address mode register	DMAMD	16	16	2 ICLK	
0008 20DCh	DMAC3	DMA transfer enable register	DMCNT	8	8	2 ICLK	
0008 20DDh	DMAC3	DMA software start register	DMREQ	8	8	2 ICLK	
0008 20DEh	DMAC3	DMA status register	DMSTS	8	8	2 ICLK	
0008 20DFh	DMAC3	DMA activation source flag control register	DMCSL	8	8	2 ICLK	
0008 2200h	DMAC	DMA module activation register	DMAST	8	8	2 ICLK	
0008 2400h	DTC	DTC control register	DTCCR	8	8	2 ICLK	
0008 2404h	DTC	DTC vector base register	DTCVBR	32	32	2 ICLK	
0008 2408h	DTC	DTC address mode register	DTCADMOD	8	8	2 ICLK	
0008 240Ch	DTC	DTC module start register	DTCST	8	8	2 ICLK	
0008 240Eh	DTC	DTC status register	DTCSTS	16	16	2 ICLK	
0008 3002h	BSC	CS0 mode register	CS0MOD	16	16	1, 2 BCLK	
0008 3004h	BSC	CS0 wait control register 1	CS0WCR1	32	32	1, 2 BCLK	
0008 3008h	BSC	CS0 wait control register 2	CS0WCR2	32	32	1, 2 BCLK	
0008 3012h	BSC	CS1 mode register	CS1MOD	16	16	1, 2 BCLK	
0008 3014h	BSC	CS1 wait control register 1	CS1WCR1	32	32	1, 2 BCLK	
0008 3018h	BSC	CS1 wait control register 2	CS1WCR2	32	32	1, 2 BCLK	
0008 3022h	BSC	CS2 mode register	CS2MOD	16	16	1, 2 BCLK	
0008 3024h	BSC	CS2 wait control register 1	CS2WCR1	32	32	1, 2 BCLK	
0008 3028h	BSC	CS2 wait control register 2	CS2WCR2	32	32	1, 2 BCLK	

Table 4.1 List of I/O Registers (Address Order) (13 / 29)

Address	Module Symbol	Register Name	Register Symbol	Number of Bits	Access Size	Number of Access Cycles	
						ICLK ≥ PCLK	ICLK < PCLK
0008 820Ah	TMR0	Timer counter control register	TCCR	8	8	2, 3 PCLKB	2 ICLK
0008 820Bh	TMR1	Timer counter control register	TCCR	8	8*1	2, 3 PCLKB	2 ICLK
0008 820Ch	TMR0	Time count start register	TCSTR	8	8	2, 3 PCLKB	2 ICLK
0008 8210h	TMR2	Timer control register	TCR	8	8	2, 3 PCLKB	2 ICLK
0008 8211h	TMR3	Timer control register	TCR	8	8	2, 3 PCLKB	2 ICLK
0008 8212h	TMR2	Timer control/status register	TCSR	8	8	2, 3 PCLKB	2 ICLK
0008 8213h	TMR3	Timer control/status register	TCSR	8	8	2, 3 PCLKB	2 ICLK
0008 8214h	TMR2	Time constant register A	TCORA	8	8	2, 3 PCLKB	2 ICLK
0008 8215h	TMR3	Time constant register A	TCORA	8	8*1	2, 3 PCLKB	2 ICLK
0008 8216h	TMR2	Time constant register B	TCORB	8	8	2, 3 PCLKB	2 ICLK
0008 8217h	TMR3	Time constant register B	TCORB	8	8*1	2, 3 PCLKB	2 ICLK
0008 8218h	TMR2	Timer counter	TCNT	8	8	2, 3 PCLKB	2 ICLK
0008 8219h	TMR3	Timer counter	TCNT	8	8*1	2, 3 PCLKB	2 ICLK
0008 821Ah	TMR2	Timer counter control register	TCCR	8	8	2, 3 PCLKB	2 ICLK
0008 821Bh	TMR3	Timer counter control register	TCCR	8	8*1	2, 3 PCLKB	2 ICLK
0008 821Ch	TMR2	Time count start register	TCSTR	8	8	2, 3 PCLKB	2 ICLK
0008 8280h	CRC	CRC control register	CRCCR	8	8	2, 3 PCLKB	2 ICLK
0008 8281h	CRC	CRC data input register	CRCDIR	8	8	2, 3 PCLKB	2 ICLK
0008 8282h	CRC	CRC data output register	CRCDOR	16	16	2, 3 PCLKB	2 ICLK
0008 8300h	RIIC0	I ² C bus control register 1	ICCR1	8	8	2, 3 PCLKB	2 ICLK
0008 8301h	RIIC0	I ² C bus control register 2	ICCR2	8	8	2, 3 PCLKB	2 ICLK
0008 8302h	RIIC0	I ² C bus mode register 1	ICMR1	8	8	2, 3 PCLKB	2 ICLK
0008 8303h	RIIC0	I ² C bus mode register 2	ICMR2	8	8	2, 3 PCLKB	2 ICLK
0008 8304h	RIIC0	I ² C bus mode register 3	ICMR3	8	8	2, 3 PCLKB	2 ICLK
0008 8305h	RIIC0	I ² C bus function enable register	ICFER	8	8	2, 3 PCLKB	2 ICLK
0008 8306h	RIIC0	I ² C bus status enable register	ICSER	8	8	2, 3 PCLKB	2 ICLK
0008 8307h	RIIC0	I ² C bus interrupt enable register	ICIER	8	8	2, 3 PCLKB	2 ICLK
0008 8308h	RIIC0	I ² C bus status register 1	ICSR1	8	8	2, 3 PCLKB	2 ICLK
0008 8309h	RIIC0	I ² C bus status register 2	ICSR2	8	8	2, 3 PCLKB	2 ICLK
0008 830Ah	RIIC0	Slave address register L0	SARL0	8	8	2, 3 PCLKB	2 ICLK
0008 830Ah	RIIC0	Timeout internal counter L	TMOCNTL	8	8	2, 3 PCLKB	2 ICLK
0008 830Bh	RIIC0	Slave address register U0	SARU0	8	8	2, 3 PCLKB	2 ICLK
0008 830Bh	RIIC0	Timeout internal counter U	TMOCNTU	8	8*2	2, 3 PCLKB	2 ICLK
0008 830Ch	RIIC0	Slave address register L1	SARL1	8	8	2, 3 PCLKB	2 ICLK
0008 830Dh	RIIC0	Slave address register U1	SARU1	8	8	2, 3 PCLKB	2 ICLK
0008 830Eh	RIIC0	Slave address register L2	SARL2	8	8	2, 3 PCLKB	2 ICLK
0008 830Fh	RIIC0	Slave address register U2	SARU2	8	8	2, 3 PCLKB	2 ICLK
0008 8310h	RIIC0	I ² C bus bit rate low-level register	ICBRL	8	8	2, 3 PCLKB	2 ICLK
0008 8311h	RIIC0	I ² C bus bit rate high-level register	ICBRH	8	8	2, 3 PCLKB	2 ICLK
0008 8312h	RIIC0	I ² C bus transmit data register	ICDRT	8	8	2, 3 PCLKB	2 ICLK
0008 8313h	RIIC0	I ² C bus receive data register	ICDRR	8	8	2, 3 PCLKB	2 ICLK
0008 8380h	RSPI0	RSPI control register	SPCR	8	8	2, 3 PCLKB	2 ICLK
0008 8381h	RSPI0	RSPI slave select polarity register	SSLP	8	8	2, 3 PCLKB	2 ICLK
0008 8382h	RSPI0	RSPI pin control register	SPPCR	8	8	2, 3 PCLKB	2 ICLK
0008 8383h	RSPI0	RSPI status register	SPSR	8	8	2, 3 PCLKB	2 ICLK
0008 8384h	RSPI0	RSPI data register	SPDR	32	16, 32	2, 3 PCLKB	2 ICLK
0008 8388h	RSPI0	RSPI sequence control register	SPSCR	8	8	2, 3 PCLKB	2 ICLK
0008 8389h	RSPI0	RSPI sequence status register	SPSSR	8	8	2, 3 PCLKB	2 ICLK
0008 838Ah	RSPI0	RSPI bit rate register	SPBR	8	8	2, 3 PCLKB	2 ICLK
0008 838Bh	RSPI0	RSPI data control register	SPDCR	8	8	2, 3 PCLKB	2 ICLK
0008 838Ch	RSPI0	RSPI clock delay register	SPCKD	8	8	2, 3 PCLKB	2 ICLK

Table 4.1 List of I/O Registers (Address Order) (14 / 29)

Address	Module Symbol	Register Name	Register Symbol	Number of Bits	Access Size	Number of Access Cycles	
						ICLK $\geq$ PCLK	ICLK < PCLK
0008 838Dh	RSPI0	RSPI slave select negation delay register	SSLND	8	8	2, 3 PCLKB	2 ICLK
0008 838Eh	RSPI0	RSPI next-access delay register	SPND	8	8	2, 3 PCLKB	2 ICLK
0008 838Fh	RSPI0	RSPI control register 2	SPCR2	8	8	2, 3 PCLKB	2 ICLK
0008 8390h	RSPI0	RSPI command register 0	SPCMD0	16	16	2, 3 PCLKB	2 ICLK
0008 8392h	RSPI0	RSPI command register 1	SPCMD1	16	16	2, 3 PCLKB	2 ICLK
0008 8394h	RSPI0	RSPI command register 2	SPCMD2	16	16	2, 3 PCLKB	2 ICLK
0008 8396h	RSPI0	RSPI command register 3	SPCMD3	16	16	2, 3 PCLKB	2 ICLK
0008 8398h	RSPI0	RSPI command register 4	SPCMD4	16	16	2, 3 PCLKB	2 ICLK
0008 839Ah	RSPI0	RSPI command register 5	SPCMD5	16	16	2, 3 PCLKB	2 ICLK
0008 839Ch	RSPI0	RSPI command register 6	SPCMD6	16	16	2, 3 PCLKB	2 ICLK
0008 839Eh	RSPI0	RSPI command register 7	SPCMD7	16	16	2, 3 PCLKB	2 ICLK
0008 8600h	MTU3	Timer control register	TCR	8	8	2, 3 PCLKB	2 ICLK
0008 8601h	MTU4	Timer control register	TCR	8	8	2, 3 PCLKB	2 ICLK
0008 8602h	MTU3	Timer mode register	TMDR	8	8	2, 3 PCLKB	2 ICLK
0008 8603h	MTU4	Timer mode register	TMDR	8	8	2, 3 PCLKB	2 ICLK
0008 8604h	MTU3	Timer I/O control register H	TIORH	8	8	2, 3 PCLKB	2 ICLK
0008 8605h	MTU3	Timer I/O control register L	TIORL	8	8	2, 3 PCLKB	2 ICLK
0008 8606h	MTU4	Timer I/O control register H	TIORH	8	8	2, 3 PCLKB	2 ICLK
0008 8607h	MTU4	Timer I/O control register L	TIORL	8	8	2, 3 PCLKB	2 ICLK
0008 8608h	MTU3	Timer interrupt enable register	TIER	8	8	2, 3 PCLKB	2 ICLK
0008 8609h	MTU4	Timer interrupt enable register	TIER	8	8	2, 3 PCLKB	2 ICLK
0008 860Ah	MTU	Timer output master enable register	TOER	8	8	2, 3 PCLKB	2 ICLK
0008 860Dh	MTU	Timer gate control register	TGCR	8	8	2, 3 PCLKB	2 ICLK
0008 860Eh	MTU	Timer output control register 1	TOCR1	8	8	2, 3 PCLKB	2 ICLK
0008 860Fh	MTU	Timer output control register 2	TOCR2	8	8	2, 3 PCLKB	2 ICLK
0008 8610h	MTU3	Timer counter	TCNT	16	16	2, 3 PCLKB	2 ICLK
0008 8612h	MTU4	Timer counter	TCNT	16	16	2, 3 PCLKB	2 ICLK
0008 8614h	MTU	Timer cycle data register	TCDR	16	16	2, 3 PCLKB	2 ICLK
0008 8616h	MTU	Timer dead time data register	TDDR	16	16	2, 3 PCLKB	2 ICLK
0008 8618h	MTU3	Timer general register A	TGRA	16	16	2, 3 PCLKB	2 ICLK
0008 861Ah	MTU3	Timer general register B	TGRB	16	16	2, 3 PCLKB	2 ICLK
0008 861Ch	MTU4	Timer general register A	TGRA	16	16	2, 3 PCLKB	2 ICLK
0008 861Eh	MTU4	Timer general register B	TGRB	16	16	2, 3 PCLKB	2 ICLK
0008 8620h	MTU	Timer subcounter	TCNTS	16	16	2, 3 PCLKB	2 ICLK
0008 8622h	MTU	Timer cycle buffer register	TCBR	16	16	2, 3 PCLKB	2 ICLK
0008 8624h	MTU3	Timer general register C	TGRC	16	16	2, 3 PCLKB	2 ICLK
0008 8626h	MTU3	Timer general register D	TGRD	16	16	2, 3 PCLKB	2 ICLK
0008 8628h	MTU4	Timer general register C	TGRC	16	16	2, 3 PCLKB	2 ICLK
0008 862Ah	MTU4	Timer general register D	TGRD	16	16	2, 3 PCLKB	2 ICLK
0008 862Ch	MTU3	Timer status register	TSR	8	8	2, 3 PCLKB	2 ICLK
0008 862Dh	MTU4	Timer status register	TSR	8	8	2, 3 PCLKB	2 ICLK
0008 8630h	MTU	Timer interrupt skipping set register	TITCR	8	8	2, 3 PCLKB	2 ICLK
0008 8631h	MTU	Timer interrupt skipping counter	TITCNT	8	8	2, 3 PCLKB	2 ICLK
0008 8632h	MTU	Timer buffer transfer set register	TBTER	8	8	2, 3 PCLKB	2 ICLK
0008 8634h	MTU	Timer dead time enable register	TDER	8	8	2, 3 PCLKB	2 ICLK
0008 8636h	MTU	Timer output level buffer register	TOLBR	8	8	2, 3 PCLKB	2 ICLK
0008 8638h	MTU3	Timer buffer operation transfer mode register	TBTM	8	8	2, 3 PCLKB	2 ICLK
0008 8639h	MTU4	Timer buffer operation transfer mode register	TBTM	8	8	2, 3 PCLKB	2 ICLK
0008 8640h	MTU4	Timer A/D converter start request control register	TADCR	16	16	2, 3 PCLKB	2 ICLK
0008 8644h	MTU4	Timer A/D converter start request cycle set register A	TADCORA	16	16	2, 3 PCLKB	2 ICLK
0008 8646h	MTU4	Timer A/D converter start request cycle set register B	TADCORB	16	16	2, 3 PCLKB	2 ICLK

Table 4.1 List of I/O Registers (Address Order) (24 / 29)

Address	Module Symbol	Register Name	Register Symbol	Number of Bits	Access Size	Number of Access Cycles	
						ICLK $\geq$ PCLKB	ICLK $<$ PCLKB
0008 C04Ch	PORTC	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C04Dh	PORTD	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C04Eh	PORTE	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C04Fh	PORTF	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C051h	PORTH	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C052h	PORTJ	Port input data register	PIDR	8	8	3 or 4 PCLKB cycles when reading, 2 or 3 PCLKB cycles when writing	3 ICLK cycles when reading, 2 ICLK cycles when writing
0008 C053h	PORTK	Port input data register	PIDR	8	8	2, 3 PCLKB	2 ICLK
0008 C054h	PORTL	Port input data register	PIDR	8	8	2, 3 PCLKB	2 ICLK
0008 C060h	PORT0	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C061h	PORT1	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C062h	PORT2	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C063h	PORT3	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C064h	PORT4	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C065h	PORT5	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C066h	PORT6	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C067h	PORT7	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C068h	PORT8	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C069h	PORT9	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Ah	PORTA	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Bh	PORTB	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Ch	PORTC	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Dh	PORTD	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Eh	PORTE	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C06Fh	PORTF	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C071h	PORTH	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C072h	PORTJ	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C073h	PORTK	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK
0008 C074h	PORTL	Port mode register	PMR	8	8	2, 3 PCLKB	2 ICLK

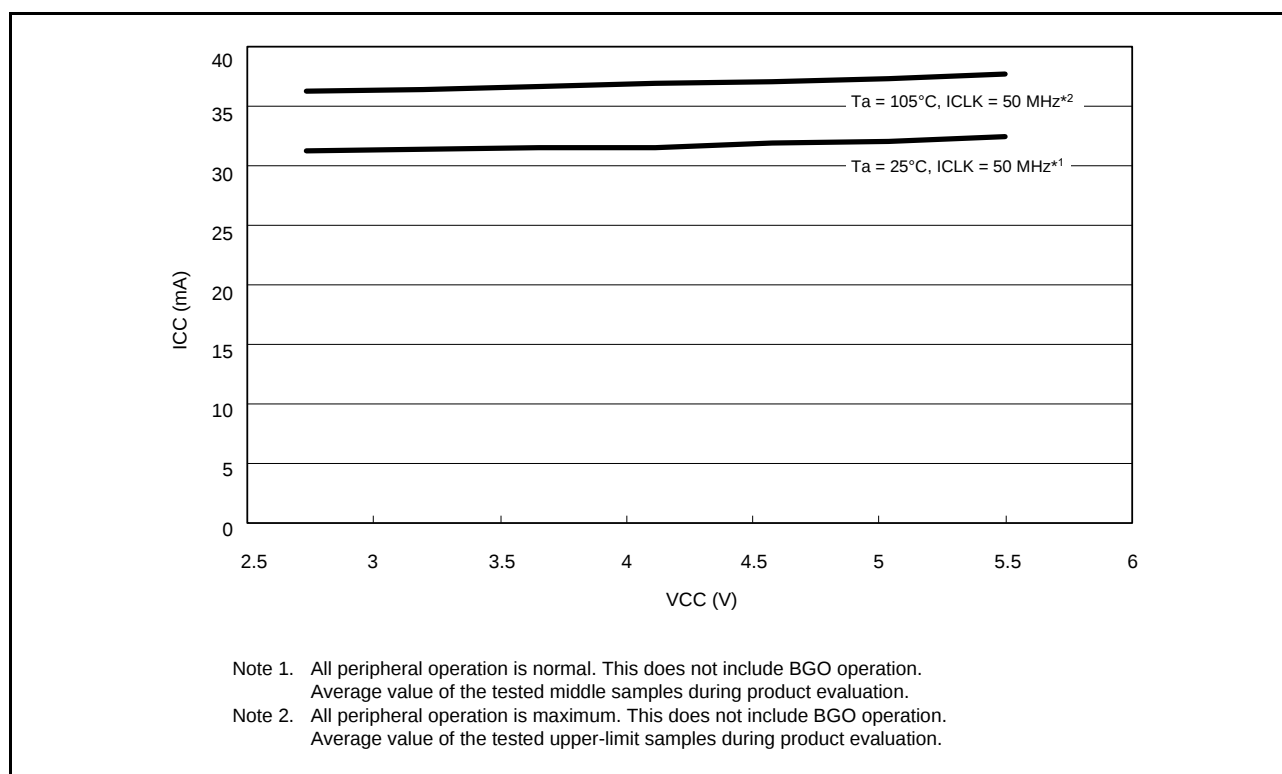


Figure 5.1 Voltage Dependency in High-Speed Operating Mode (Reference Data) for Chip Version A

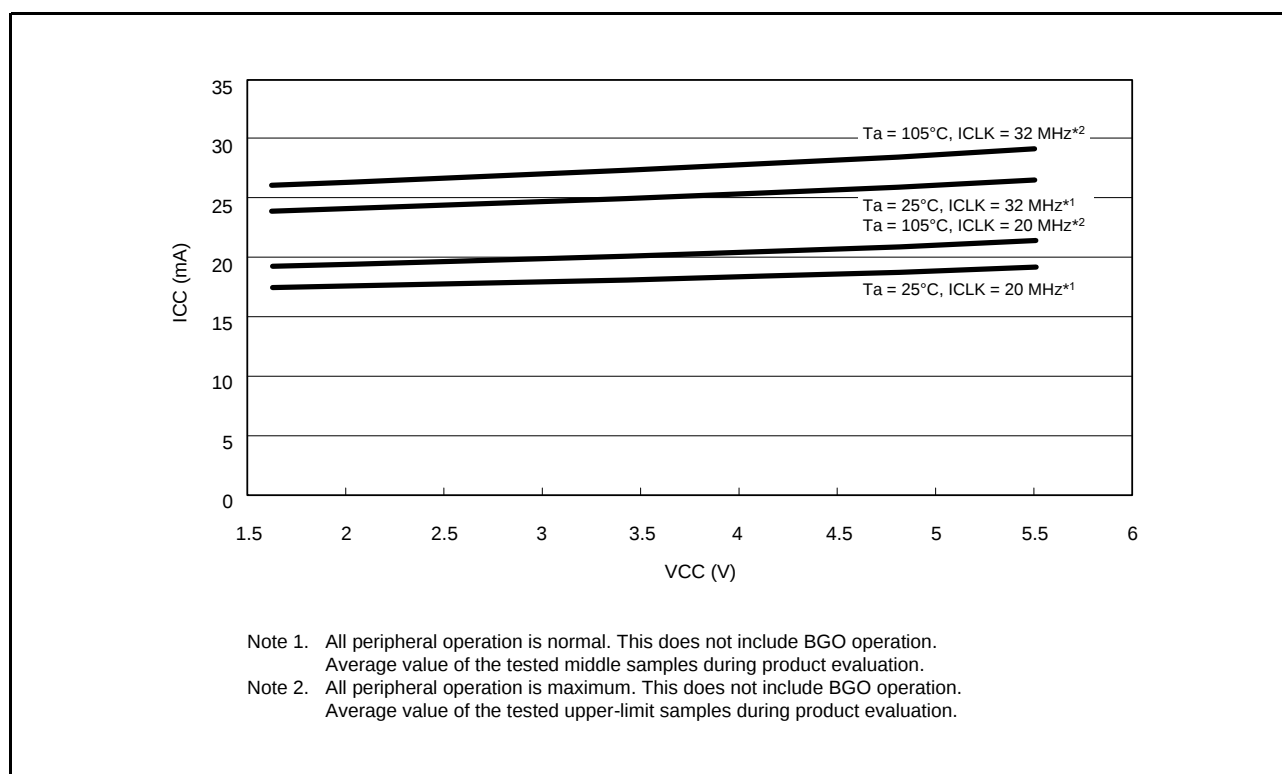


Figure 5.2 Voltage Dependency in Middle-Speed Operating Modes 1A and 1B (Reference Data) for Chip Version A

[Chip version C]

Table 5.9 DC Characteristics (8)Conditions: $V_{CC} = AVCC0 = 2.7$ to 5.5 V, $V_{SS} = AVSS0 = VREFL = VREFL0 = 0$ V, $T_a = -40$ to $+105^\circ\text{C}$

Item					Symbol	Typ.	Max.	Unit	Test Conditions
Supply current*1	High-speed operating mode	Normal operating mode	No peripheral operation*2	ICLK = 50 MHz	I _{CC}	10	—	mA	
			All peripheral operation: Normal*3	ICLK = 50 MHz		31.5	—		
			All peripheral operation: Max.*3	ICLK = 50 MHz		—	55		
		Sleep mode	No peripheral operation	ICLK = 50 MHz		7.5	—		
			All peripheral operation: Normal	ICLK = 50 MHz		17.5	—		
		All-module clock stop mode		ICLK = 50 MHz		6.7	—		
		Increase during BGO operation*4				25	—		

Note 1. Supply current values do not include output charge/discharge current from all pins. The values apply when internal pull-up MOSs are in the off state.

Note 2. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 100 MHz. BCLK, FCLK, and PCLK are set to divided by 64.

Note 3. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 100 MHz. BCLK, FCLK, and PCLK are ICLK divided by 2.

Note 4. This is the increase if data is programmed to or erasing from the ROM or E2 DataFlash during program execution.

Item					Symbol	Typ.	Max.	Unit	Test Conditions	
Supply current*1	Low-speed operating mode 1	Normal operating mode	No peripheral operation*7	ICLK = 8 MHz	I _{CC}	2.1	—	mA		
				ICLK = 4 MHz		1.7	—			
				ICLK = 2 MHz		1.5	—			
			All peripheral operation: Normal*8	ICLK = 8 MHz		7.3	—			
				ICLK = 4 MHz		4.5	—			
				ICLK = 2 MHz		3.1	—			
			All peripheral operation: Max.*7	ICLK = 8 MHz		—	12			
				ICLK = 4 MHz		—	—			
				ICLK = 2 MHz		—	—			
		Sleep mode	No peripheral operation	ICLK = 8 MHz		1.5	—			
				ICLK = 4 MHz		1.4	—			
				ICLK = 2 MHz		1.3	—			
			All peripheral operation: Normal	ICLK = 8 MHz		4.1	—			
				ICLK = 4 MHz		3.0	—			
				ICLK = 2 MHz		2.3	—			
		All-module clock stop mode				ICLK = 8 MHz	1.4			—
						ICLK = 4 MHz	1.3			—
						ICLK = 2 MHz	1.2			—
	Low-speed operating mode 2	Normal operating mode	No peripheral operation*9	ICLK = 32 kHz		0.022	—			
				ICLK = 32 kHz		0.06	—			
			All peripheral operation: Normal*10	ICLK = 32 kHz		—	3*11			
		Sleep mode	No peripheral operation	ICLK = 32 kHz		0.017	—			
				ICLK = 32 kHz		0.036	—			
		All-module clock stop mode				ICLK = 32 kHz	0.017			—
						ICLK = 32 kHz	0.017			—

Note 1. Supply current values do not include output charge/discharge current from all pins. The values apply when internal pull-up MOSs are in the off state.

Note 2. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 64 MHz. BCLK, FCLK, and PCLK are set to divided by 64.

Note 3. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is HOCO and the oscillation frequency is 40 MHz. BCLK, FCLK, and PCLK are set to divided by 64.

Note 4. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 64 MHz. BCLK, FCLK, and PCLK are ICLK divided by 1.

Note 5. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is HOCO and the oscillation frequency is 40 MHz. BCLK, FCLK, and PCLK are ICLK divided by 1.

Note 6. This is the increase if data is programmed to or erasing from the ROM or E2 DataFlash during program execution.

Note 7. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is HOCO and the oscillation frequency is 32 MHz. BCLK, FCLK, and PCLK are set to divided by 64.

Note 8. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is HOCO and the oscillation frequency is 32 MHz. BCLK, FCLK, and PCLK are ICLK divided by 1.

Note 9. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is the sub oscillation circuit. BCLK, FCLK, and PCLK are set to divided by 64.

Note 10. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is the sub oscillation circuit. BCLK, FCLK, and PCLK are ICLK divided by 1.

Note 11. Value when the main clock continues oscillating at 12.5 MHz.

[Chip version B with 512 Kbytes or less of flash memory and 144 and 145 pins]

Table 5.18 DC Characteristics (17)

Conditions: $V_{CC} = AVCC0 = 2.7$ to 5.5 V, $V_{SS} = AVSS0 = VREFL = VREFL0 = 0$ V, $T_a = -40$ to $+105^\circ\text{C}$

Item					Symbol	Typ.	Max.	Unit	Test Conditions	
Supply current*1	High-speed operating mode	Normal operating mode	No peripheral operation*2	ICLK = 50 MHz	I _{CC}	7.2	—	mA		
			All peripheral operation: Normal*3	ICLK = 50 MHz		25.9	—			
			All peripheral operation: Max.*3	ICLK = 50 MHz		—	45			
		Sleep mode	No peripheral operation	ICLK = 50 MHz		4.3	—			
			All peripheral operation: Normal	ICLK = 50 MHz		13	—			
		All-module clock stop mode				3.7	—			
		Increase during BGO operation*4				21	—			

Note 1. Supply current values do not include output charge/discharge current from all pins. The values apply when internal pull-up MOSs are in the off state.

Note 2. Clock supply to the peripheral functions is stopped. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 100 MHz. BCLK, FCLK, and PCLK are set to divided by 64.

Note 3. Clocks are supplied to the peripheral functions. This does not include BGO operation. The clock source is PLL and the VCO oscillation frequency is 100 MHz. BCLK, FCLK, and PCLK are ICLK divided by 2.

Note 4. This is the increase if data is programmed to or erasing from the ROM or E2 DataFlash during program execution.

[Chip version B with 512 Kbytes or less of flash memory and 144 and 145 pins]

Table 5.19 DC Characteristics (18)Conditions: $V_{CC} = AVCC0 = 1.62$ to 5.5 V, $V_{SS} = AVSS0 = V_{REFL} = V_{REFL0} = 0$ V, $T_a = -40$ to $+105^{\circ}\text{C}$

Item					Symbol	Typ.	Max.	Unit	Test Conditions	
Supply current*1	Middle-speed operating modes 1A and 1B	Normal operating mode	No peripheral operation	ICLK = 32 MHz*2	I _{CC}	5.3	—	mA		
				ICLK = 20 MHz*3		4.6	—			
			All peripheral operation: Normal	ICLK = 32 MHz*4		22.3	—			
				ICLK = 20 MHz*5		15.6	—			
			All peripheral operation: Max.	ICLK = 32 MHz*4		—	35			
				ICLK = 20 MHz*5		—	—			
		Sleep mode	No peripheral operation	ICLK = 32 MHz		3.4	—			
				ICLK = 20 MHz		3.3	—			
			All peripheral operation: Normal	ICLK = 32 MHz		12.8	—			
				ICLK = 20 MHz		9.8	—			
		All-module clock stop mode				ICLK = 32 MHz	3			—
						ICLK = 20 MHz	3			—
		Increase during BGO operation*6	Middle-speed operating mode 1A			21	—			
			Middle-speed operating mode 1B			19	—			
	Middle-speed operating modes 2A and 2B	Normal operating mode	No peripheral operation*2	ICLK = 32 MHz		4.7	—			
				ICLK = 16 MHz		3.4	—			
				ICLK = 8 MHz		2.7	—			
			All peripheral operation: Normal*4	ICLK = 32 MHz*3		21.7	—			
				ICLK = 16 MHz*3		12.3	—			
				ICLK = 8 MHz		7.6	—			
			All peripheral operation: Max.*4	ICLK = 32 MHz*3		—	34			
				ICLK = 16 MHz*3		—	—			
				ICLK = 8 MHz		—	—			
		Sleep mode	No peripheral operation	ICLK = 32 MHz		2.9	—			
				ICLK = 16 MHz		2.5	—			
				ICLK = 8 MHz		2.2	—			
			All peripheral operation: Normal	ICLK = 32 MHz		12.3	—			
				ICLK = 16 MHz		7.8	—			
				ICLK = 8 MHz		5.6	—			
		All-module clock stop mode				ICLK = 32 MHz	2.5			—
						ICLK = 16 MHz	2.2			—
						ICLK = 8 MHz	2.1			—
		Increase during BGO operation*6	Middle-speed operating mode 1A			21	—			
			Middle-speed operating mode 1B			19	—			

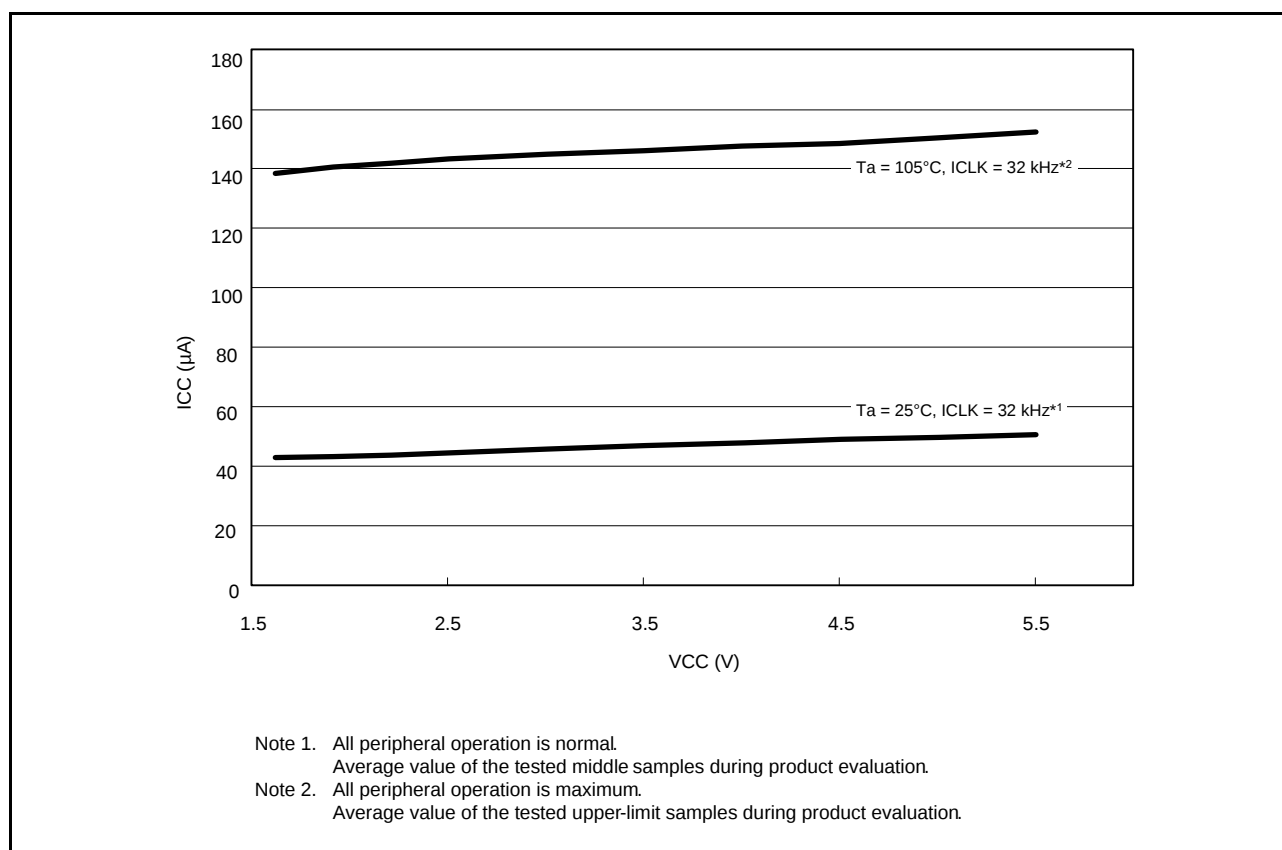


Figure 5.39 Voltage Dependency in Low-Speed Operating Mode 2 (Reference Data) for Chip Version B with 512 Kbytes or Less of Flash Memory and 144 and 145 Pins

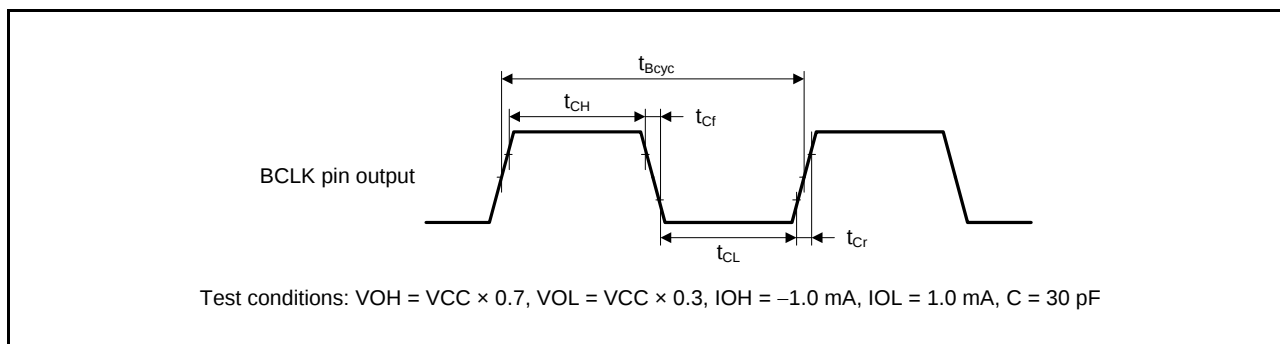


Figure 5.59 BCLK Pin Output Timing

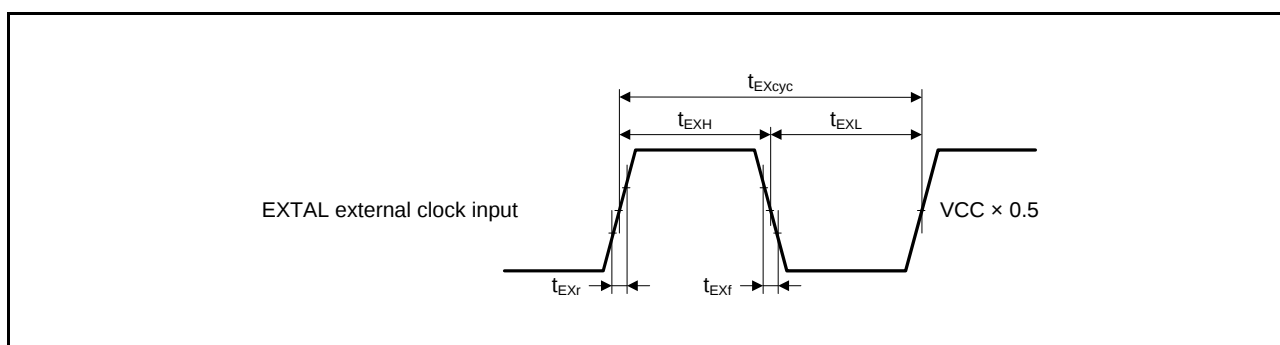


Figure 5.60 EXTAL External Clock Input Timing

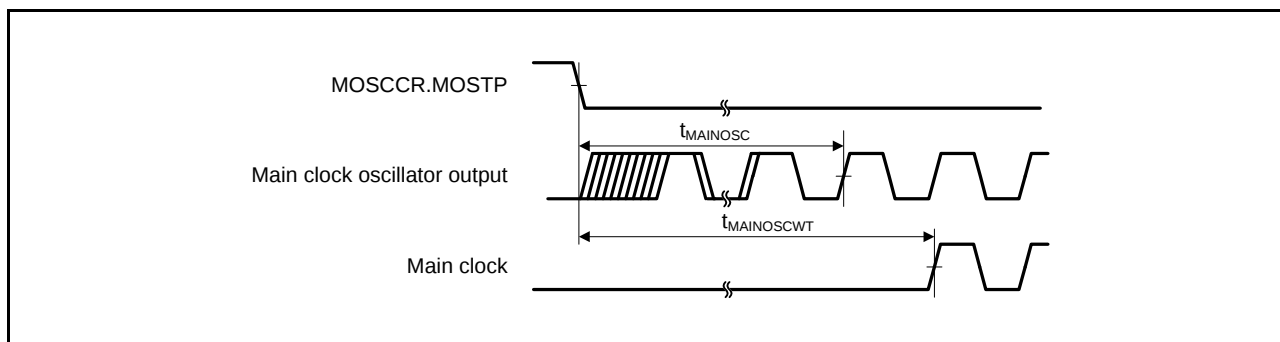


Figure 5.61 Main Clock Oscillation Start Timing

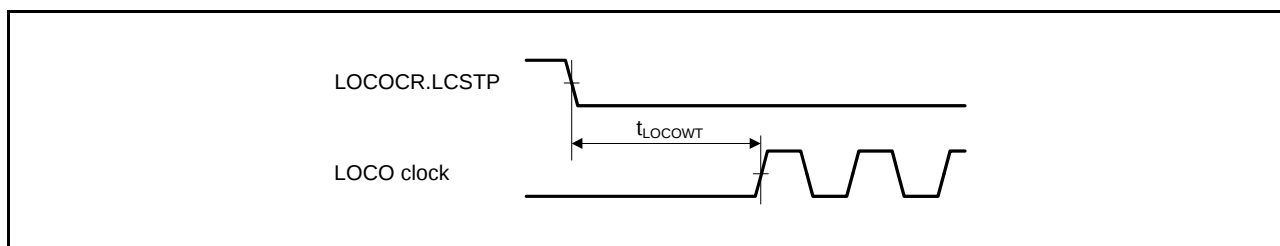


Figure 5.62 LOCO Clock Oscillation Start Timing

Table 5.51 Bus Timing (3)

Conditions: $V_{CC} = AVCC0 = 1.62$ to 1.8 V, $V_{SS} = AVSS0 = V_{REFL} = V_{REFL0} = 0$ V,
 $f_{BCLK} \leq 12$ MHz (BCLK pin output frequency ≤ 6 MHz), $T_a = -40$ to $+105^\circ\text{C}$, $V_{OH} = V_{CC} \times 0.5$,
 $V_{OL} = V_{CC} \times 0.5$, $I_{OH} = -0.5$ mA, $I_{OL} = 0.5$ mA, $C_L = 30$ pF
 When normal output is selected by the drive capacity register

Item	Symbol	Min.	Max.	Unit	Test Conditions
Address delay time	t_{AD}	—	125	ns	Figure 5.76 to Figure 5.79
Byte control delay time	t_{BCD}	—	125	ns	
CS# delay time	t_{CSD}	—	125	ns	
RD# delay time	t_{RSD}	—	125	ns	
Read data setup time	t_{RDS}	85	—	ns	
Read data hold time	t_{RDH}	0	—	ns	
WR# delay time	t_{WRD}	—	125	ns	
Write data delay time	t_{WDD}	—	125	ns	
Write data hold time	t_{WDH}	0	—	ns	
WAIT# setup time	t_{WTS}	85	—	ns	Figure 5.80
WAIT# hold time	t_{WTH}	0	—	ns	

Table 5.54 Bus Timing (Multiplexed Bus) (3)

Conditions: $V_{CC} = AVCC0 = 1.62$ to 1.8 V, $V_{SS} = AVSS0 = V_{REFL} = V_{REFL0} = 0$ V,
 $f_{BCLK} \leq 12$ MHz (BCLK pin output frequency ≤ 6 MHz), $T_a = -40$ to $+105^\circ\text{C}$, $V_{OH} = V_{CC} \times 0.5$,
 $V_{OL} = V_{CC} \times 0.5$, $I_{OH} = -0.5$ mA, $I_{OL} = 0.5$ mA, $C_L = 30$ pF
 When normal output is selected by the drive capacity register

Item	Symbol	Min.	Typ.	Max.	Unit
Address delay time	t_{AD}	—	125	ns	Figure 5.81 and Figure 5.82
Byte control delay time	t_{BCD}	—	125	ns	
CS# delay time	t_{CSD}	—	125	ns	
RD# delay time	t_{RSD}	—	125	ns	
ALE delay time	t_{ALED}	—	125	ns	
Read data setup time	t_{RDS}	85	—	ns	
Read data hold time	t_{RDH}	0	—	ns	
WR# delay time	t_{WRD}	—	125	ns	
Write data delay time	t_{WDD}	—	125	ns	
Write data hold time	t_{WDH}	0	—	ns	
WAIT# setup time	t_{WTS}	85	—	ns	Figure 5.80
WAIT# hold time	t_{WTH}	0	—	ns	

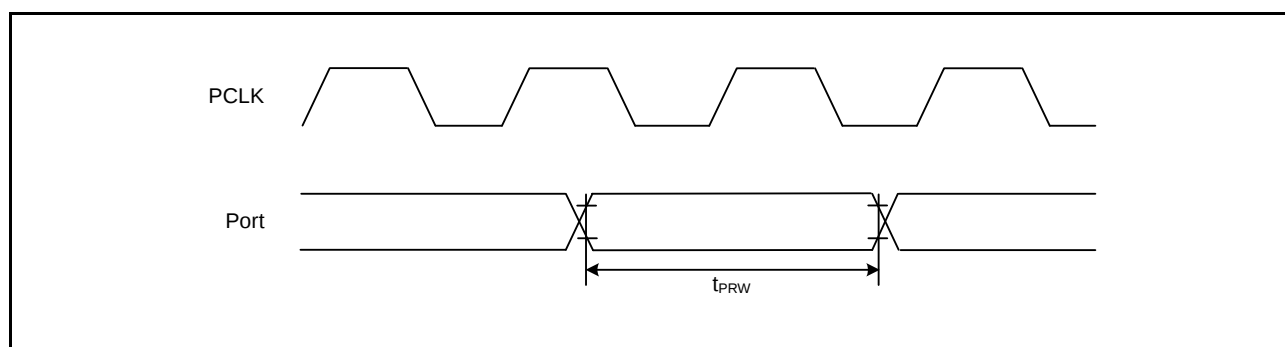


Figure 5.83 I/O Port Input Timing

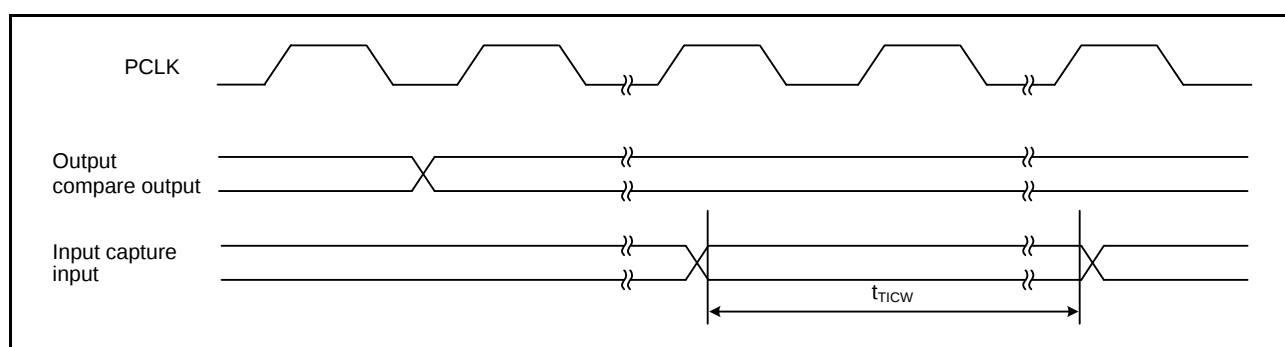


Figure 5.84 MTU/TPU Input/Output Timing

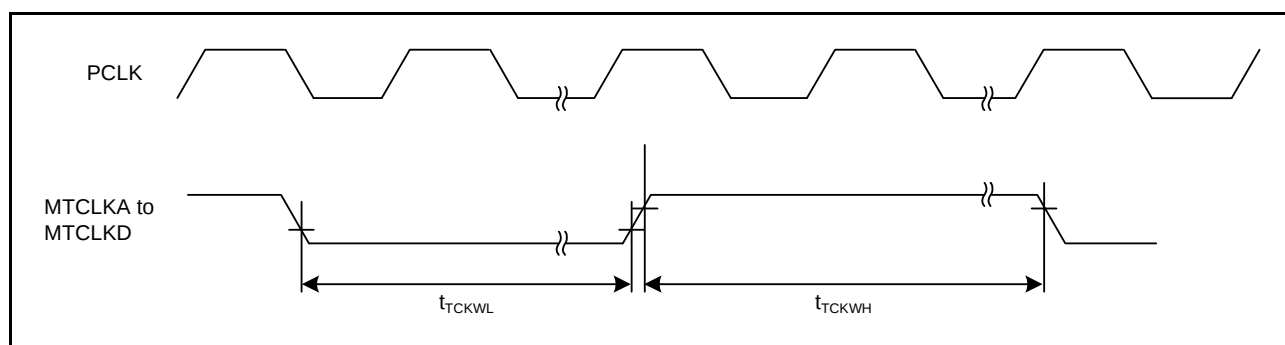


Figure 5.85 MTU/TPU Clock Input Timing

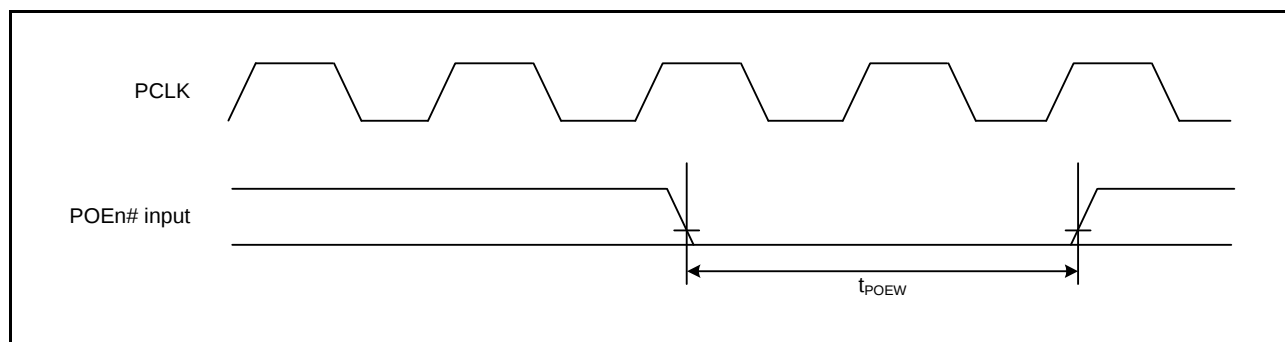


Figure 5.86 POE# Input Timing

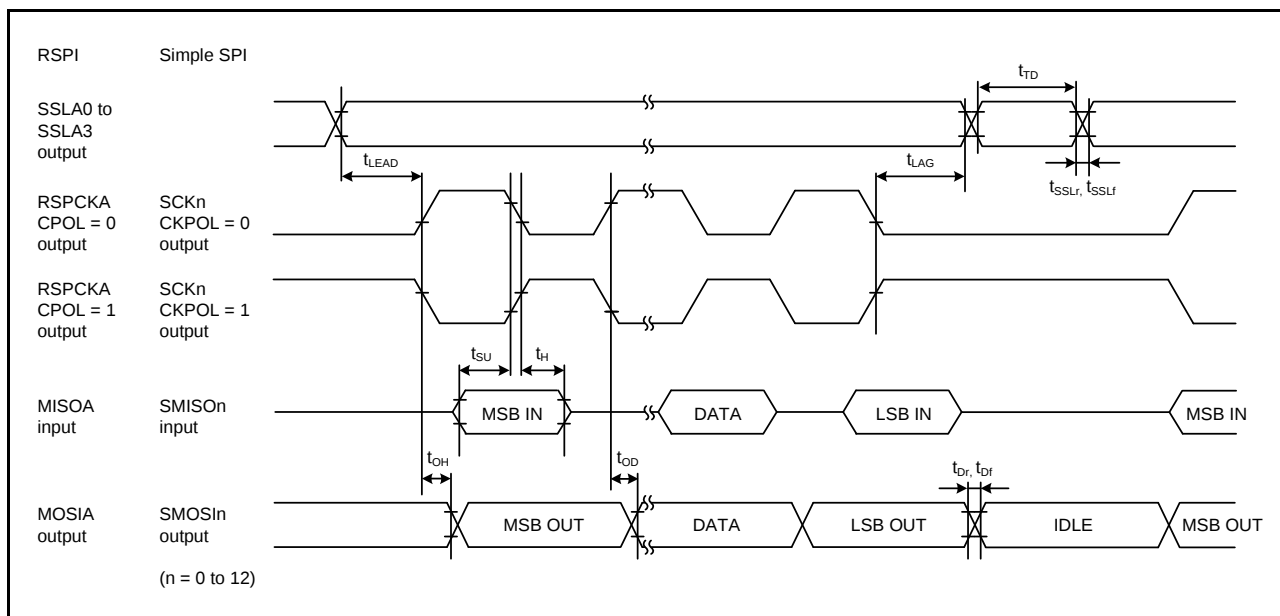


Figure 5.94 RSPI Timing (Master, CPHA = 1) (Bit Rate: PCLKB Set to Division Ratio Other Than Divided by 2) and Simple SPI Timing (Master, CKPH = 0)

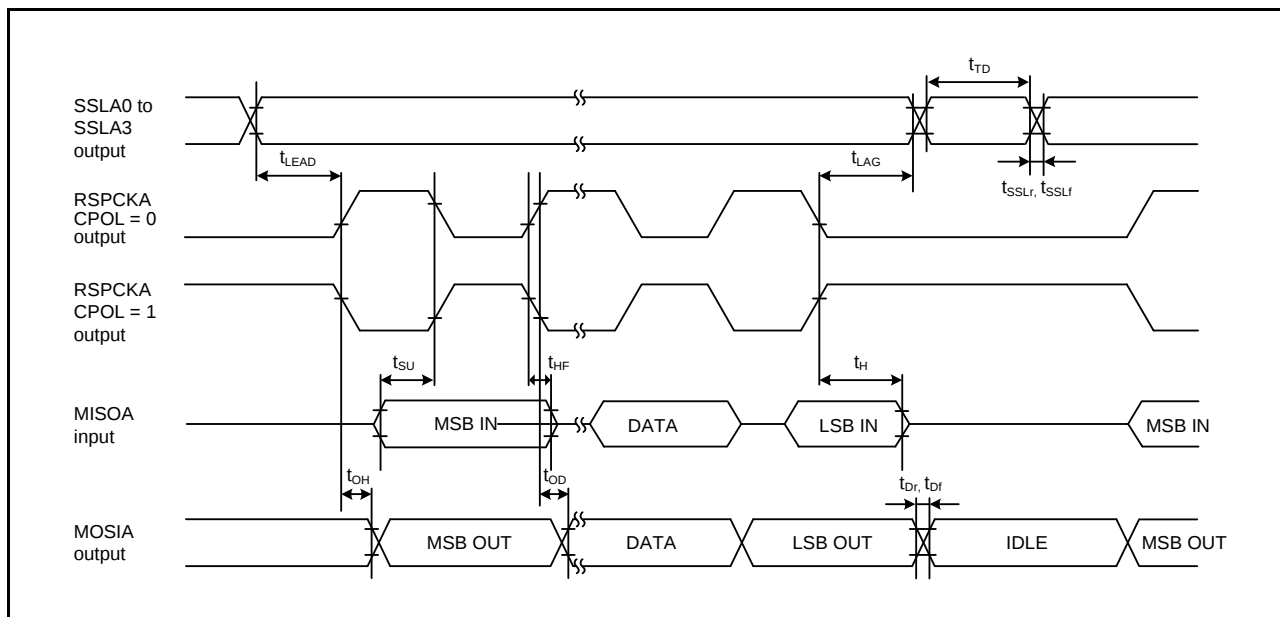
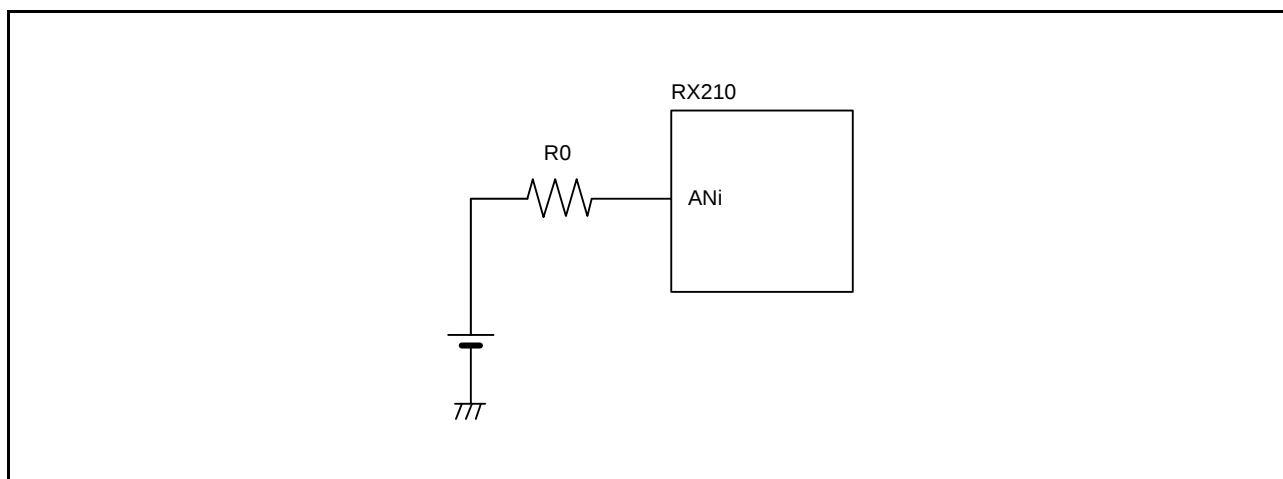


Figure 5.95 RSPI Timing (Master, CPHA = 1) (Bit Rate: PCLKB Set to Divided by 2)

Table 5.66 Sampling TimeConditions: $V_{CC} = AV_{CC0} = 1.62$ to 5.5 V, $V_{SS} = AV_{SS0} = V_{REFL} = V_{REFL0} = 0$ V, $T_a = -40$ to $+105^{\circ}\text{C}$

Item		Symbol	Typ.	Unit	Test Conditions
Sampling time	High-precision channel	T_s	$0.2 + 0.14 \times R_0$ (K Ω)	μs	Figure 5.100
	Normal-precision channel		$0.35 + 0.14 \times R_0$ (K Ω)		

**Figure 5.100 Internal Equivalent Circuit of Analog Input Pin**

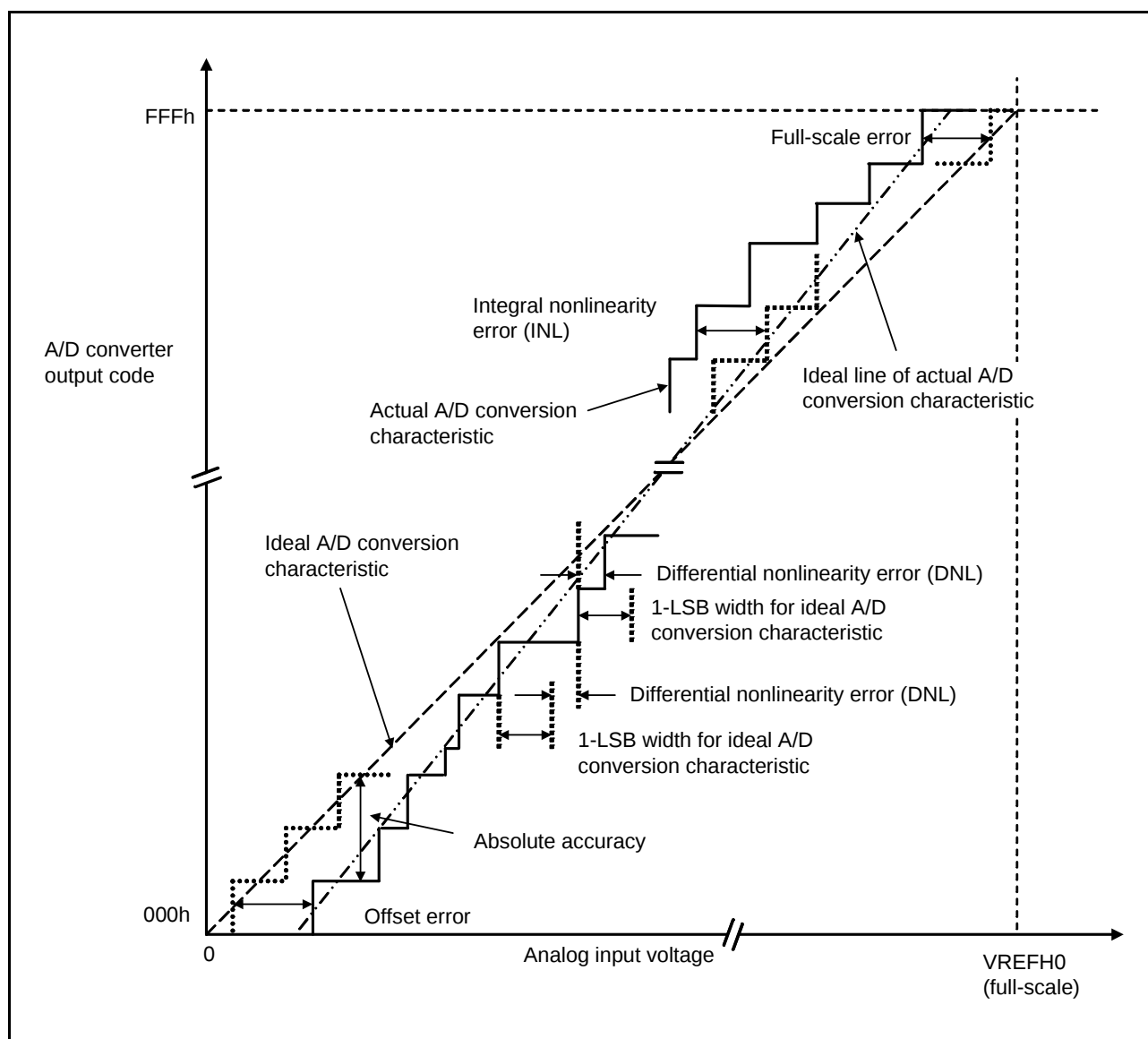


Figure 5.101 Illustration of A/D Converter Characteristic Terms

Absolute accuracy

Absolute accuracy is the difference between output code based on the theoretical A/D conversion characteristics, and the actual A/D conversion result. When measuring absolute accuracy, the voltage at the midpoint of the width of analog input voltage (1-LSB width), that can meet the expectation of outputting an equal code based on the theoretical A/D conversion characteristics, is used as an analog input voltage. For example, if 12-bit resolution is used and if reference voltage ($V_{REFH0} = 5.12 \text{ V}$), then 1-LSB width becomes 1.25 mV, and 0 mV, 1.25 mV, 2.5 mV, ... are used as analog input voltages.

If analog input voltage is 10 mV, absolute accuracy = $\pm 5 \text{ LSB}$ means that the actual A/D conversion result is in the range of 003h to 00Dh though an output code, 008h, can be expected from the theoretical A/D conversion characteristics.

Integral nonlinearity error (INL)

Integral nonlinearity error is the maximum deviation between the ideal line when the measured offset and full-scale errors are zeroed, and the actual output code.

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		Page	Summary
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		12	Figure 1.1 How to Read the Product Part No., Memory Capacity, and Package Type, changed
		13	Figure 1.2 Block Diagram, changed
		14 to 17	Table 1.8 Pin Functions, changed
		18	Figure 1.3 Pin Assignments of the 145-Pin TFLGA (Upper Perspective View), added
		19	Figure 1.4 Pin Assignments of the 144-Pin LQFP, added
		25 to 28	Table 1.9 List of Pins and Pin Functions (145-Pin TFLGA), changed
		29 to 32	Table 1.10 List of Pins and Pin Functions (144-Pin LQFP), changed
		3. Address Space	
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		160, 161	[768 Kbytes/1 Mbyte of flash memory or 145/145 pins] Table 5.57 Timing of On-Chip Peripheral Modules (3), added
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		166	Figure 5.79 SCK Clock Input Timing, Figure 5.80 SCI Input/Output Timing: Clock Synchronous Mode, changed
		167	Figure 5.82 RSPI Clock Timing and Simple SPI Clock Timing, changed
		168	Figure 5.83 RSPI Timing (Master, CPHA = 0) and Simple SPI Timing (Master, CKPH = 1), Figure 5.84 RSPI Timing (Master, CPHA = 0) (Bit Rate: PCLKB Set to Divided by 2), changed
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		10	Table 1.5 List of Products Chip Version B: G Version (Ta = -40 to +105°C), changed Note, added
		11	Table 1.6 List of Products Chip Version C: D Version (Ta = -40 to +85°C): Note 1, Table 1.7 List of Products Chip Version C: G Version (Ta = -40 to +105°C): Note 1 deleted, Note added
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Renesas Electronics America Inc.
2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A.
Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd.
80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949
Tel: +65-6213-0200, Fax: +65-6213-0300

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Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia
Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

Renesas Electronics Korea Co., Ltd.
11F., Samik Laved' or Bldg., 720-2 Yeoksam-Dong, Kangnam-Ku, Seoul 135-080, Korea
Tel: +82-2-558-3737, Fax: +82-2-558-5141